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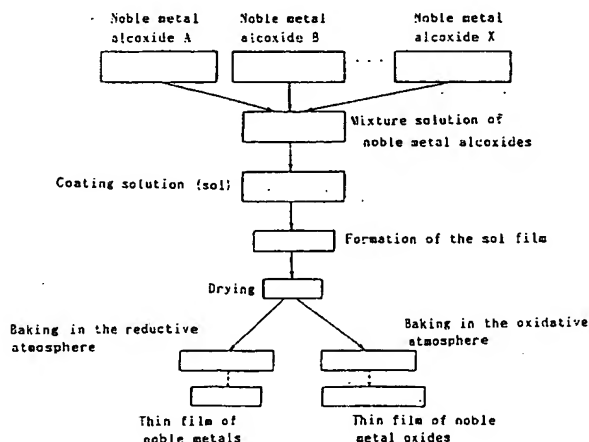
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Mauerkircherstrasse 45
W-8000 München 80(DE)(54) **Method of producing metallic thin film.**

(57) A thin film of a solution of at least one noble metal alcoxide is formed on a substrate, then dried and baked either in a reductive atmosphere to produce a thin film of metals or in an oxidative atmosphere to form a thin film of metal oxides. Said solution of noble metal alcoxides may contain merely a single component or a plurality of components. In addition, a solution of metal alcoxides containing at least one noble metal alcoxide as main component or as additive in minor amounts may be used in place of the solution of noble metal alcoxides. Said thin film of metals or metal oxides can be formed as a single layer or as a plurality of layers.

Since the thin film formed on said substrate is baked in said reductive or oxidative atmosphere, not only a single-component thin film but also a multi-component thin film can be inexpensively formed without using a complicated and large-scaled apparatus. In addition, since a solution is used, it is also possible to control the crystalline and amorphous structure of noble metal alcoxides or metal alcoxides or the compactness in the case where a porous thin film is formed.

Fig.1

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Background of the Invention

Field of the Invention

The present invention relates to a method of producing a metallic thin film, in which a thin film is formed on a substrate by the use of noble metal alcoxides alone or metal alcoxides containing noble metal alcoxides as main components or as additives in minor amounts. The metallic thin film is used, for example, in a pH-response sensor, a hydrogen sensor, gas sensors and other kinds of various applications.

Description of the Prior Art

As methods of forming a metallic thin film on a surface of a substrate there have been well known, for example, an evaporation method, in which a target set within a vacuum bell jar is heated to be vaporized, followed by depositing the resulting vapor on a substrate while forming a thin film; a sputtering method, in which a target within a vacuum bell jar is stuck to a substrate by a glow discharge to form a thin film; or a method in which a substrate is immersed in a metallic melt to form a thin film, followed by drying and then baking, whereby a metallic film is formed.

Said vapor deposition method or said sputtering method is advantageous in that the thin film can be prepared with uniform thickness or in that impurities can be removed. When taking oxides as an object, the sputtering method is suitable for high-melting-point substances. However, problems have occurred in that, since the thin film is formed within a vacuum bell jar in said methods, a complicated and expensive apparatus is required. If oxides are used as the target, it is necessary to regulate said oxides in purity; and if the target is porous, a pretreatment is required. Moreover, problems have occurred also in that in the case where a thin film of multi-component metals or metal oxides is formed, it is necessary to prepare various kinds of target. For vapor depositing or sputtering said various kinds of target simultaneously or in turn, a still more expensive apparatus is required.

Summary of the Invention

It is an object of the present invention to provide a method of producing a metallic thin film which is simple and inexpensive and which allows the formation of a thin film of mono-component or multi-component noble metals or noble metal oxides.

According to a first aspect, the present invention provides a method of producing a metallic thin film, which is characterized in that a thin film of a

solution of at least one noble metal alcoxide is formed on a substrate, then dried, and baked either in a reductive atmosphere to form a thin film of noble metals or in an oxidative atmosphere to form a thin film of noble metal oxides.

According to a second aspect, the method of the invention is characterized in that metal alcoxides containing at least one noble metal alcoxide as main component or as additives in minor amounts are used in place of said solution of noble metal alcoxides according to said first aspect of the invention.

For example, Au, Pt, Pd, Rh, Ir, Ru, Os or Ag can be optionally used as said noble metals and a coating solution comprising these noble metal alcoxides may contain merely a single component or a plurality of components. At least one thin layer of metals or metal oxides consisting of noble metals alone or mainly of noble metals or containing noble metals in minor amounts can be piled up in optional combination.

In addition, in the case where the noble metal alcoxides are used as said main components, or as additives in minor amounts, other metal alcoxides as the main components or the additives can be optionally selected depending upon the use of the thin film.

Said substrate can be optionally selected depending upon the use of the thin film. It can be made of, for example, Si or metals such as Al, Au, Ti and Ta.

If it is desired to pile up a plurality of layers of thin film on said substrate, a thin film of a solution of at least one metal alcoxide is formed again on said thin film of metal or metal oxides formed on the substrate, before baking it in said reductive or oxidative atmosphere.

The method of forming the thin film from said solution of at least one metal alcoxide can be optionally selected. For example, an application by spraying and other optional means, a drawing-up method, in which the substrate is immersed in the solution of noble metal alcoxides to be drawn up or a spin coating method, in which the solution of noble metal alcoxides is fallen on a rotating substrate drop by drop to form the thin film by a centrifugal force.

According to a third aspect, the method of the invention is characterized in that before baking, the film formation is repeated at least one times to pile-up a plurality of metallic thin film layers on said substrate.

According to said first aspect of the invention, the thin film of the solution of noble metal alcoxides is formed, for example, by applying a solution obtained by adding solvents to noble metal alcoxides (sol) to a surface of the substrate followed by drying. In the formation of the noble metallic thin

film, the dried thin film is baked at a desired temperature in a reductive atmosphere. In the formation of the thin layer of noble metal oxides, the above described dried thin film is baked in an oxidative atmosphere.

According to said second aspect of the invention, said thin film of a solution obtained by adding base metal alcoxides, which are selected depending upon the intended use of the film, to the noble metal alcoxides as the main components or the thin film of a solution containing said base metal alcoxides as the main components and the noble metal alcoxides as the additives in minor amounts is formed on the substrate. Then, the thin film formed on the substrate is baked in the same manner as in the first method of the invention to form the metallic thin film or the metal oxide thin film containing the noble metals as main components or as additives in minor amounts.

According to said third aspect of the invention, said thin film of metal alcoxides is formed again on the metallic thin film or the metal oxide thin film formed on the substrate before baking it in the reductive or oxidative atmosphere, whereby piled-up thin films comprising a plurality of layers are formed.

Brief Description of the Drawings

Fig. 1 is a flow chart schematically showing the present invention;

Figs. 2 is a schematic drawing showing a spin coating apparatus used in a first preferred embodiment;

Fig. 3 is an enlarged front view showing a substrate in said first preferred embodiment;

Fig. 4 is a perspective view showing thin film-forming means used in a second preferred embodiment; and

Fig. 5 is an enlarged front view showing a substrate in said second preferred embodiment.

Detailed Description of the Preferred Embodiments

An outline of a preferred embodiment of a method of producing a metallic thin film according to the present invention will be described below with reference to said flow chart shown in Fig. 1.

At first, a noble metal alcoxide mixture comprising noble metal alcoxides A, B ... X selected depending upon the intended use at a desired ratio is dissolved, for example, in organic solvents, to form a mixture solution of noble metal alcoxides (sol) and the resulting mixture solution of noble metal alcoxides is sufficiently stirred to prepare a coating solution with the components homogenized. Then, a thin film of said coating solution is formed on the surface of a substrate, made, for

example, of Si. The means of forming the thin film from the coating solutions is optionally selected.

Subsequently, the thin film of the coating solution is dried, for example, by heating. Since the thin film is gelatinized by this heating, the dried thin film is baked in a reductive atmosphere to form a thin film consisting of a plurality of noble metals, or is baked in an oxidative atmosphere to form a thin film consisting of a plurality of noble metal oxides (the first aspect of the invention).

It is also possible to form a thin film consisting only of one kind of noble metal or noble metal oxide by the use of anyone kind of noble metal alcoxide selected from a plurality of noble metal alcoxides A, B ... X (the first aspect of the invention).

In addition, although a plurality of noble metal alcoxides A, B ... X are mixed and dissolved to form the coating solution in the flow chart shown in Fig. 1, it is for example also possible that the respective solutions of the noble metal alcoxides A, B ... X may be prepared and then mixed.

Further, although a plurality of merely noble metal alcoxides are used in the flow chart shown in Fig. 1, it is also possible to form a thin film consisting of a plurality of kinds of metals or metal oxides containing noble metals from a coating solution prepared by mixing at least one of these noble metal alcoxides A, B ... X with base metal alcoxides suitably selected (the second aspect of the invention).

In addition, it is also possible to form a multi-layer thin film by repeating the formation of the thin film consisting of metals or metal oxides, as described above (the third aspect of the invention).

Next, a first preferred embodiment using platinum as the noble metal is described with reference to Figs. 2, 3(A) and 3(B). This first preferred embodiment corresponds to the first aspect of the invention and the third aspect of the invention).

Referring to Fig. 2, reference numeral 1 designates a spin coating apparatus comprising a turning table 2 revolved by means of a motor (not shown) and a nozzle 3 arranged above a center of said turning table 2 for falling the coating solution drop by drop.

Platinum alcoxides [Pt - (O - R)] (R: - CH₃, - C₂H₅, - C₃H₇) are dissolved in dehydrated ethyl alcohol in a quantity of 2.5 % by weight and a quantity equivalent in mol to said alcoxides of acetic acid is added to the resulting solution as a catalyst. This composition is sufficiently stirred and mixed in a stream of nitrogen gas, so as to be not brought into contact with moisture, whereby a first coating solution is prepared.

Subsequently, a substrate 4 made of Si is set at said central portion of the turning table 2 to revolve said substrate 4 at about 4,000 rpm to-

gether with the turning table 2. Then said first coating solution 5 is fallen on the substrate 4 from said nozzle 3 drop by drop at a rate of 100 to 200 μ l/about 30 seconds followed by spin coating the first coating solution on a surface of the substrate 4 to form a thin film 6a. Said thin film 6a formed on the substrate 4 in the above described manner is dried for 30 minutes at 100 to 150 °C and then baked for 30 minutes at 600 °C in a reductive atmosphere to form a Pt thin film 6b on said surface of the substrate 4, as shown in Fig. 3(A).

In addition, a second coating solution containing platinum alcoxides in a concentration of 5 % by weight is prepared similarly to the first coating solution 5. The substrate 4 shown in Fig. 3(A) is set again on the turning table 2 with said Pt thin film 6b on an upper side (not shown) to spin coat said second coating solution on the Pt thin film 6b under the same conditions as in the spin coating of the first coating solution 5, whereby a thin film 7a consisting of the second coating solution on the Pt thin film 6b is formed, as shown in Fig. 3 (B), followed by drying said thin film 7a under the same conditions as for the thin film 6a. Subsequently, the thin film 7a is baked for 30 minutes at 350 °C in an oxidative atmosphere to form a PtO thin film 7b, whereby the thin film consisting of noble metals and the thin film consisting of noble metal oxides are formed in superposed layers on the substrate 4.

The thin film 6a and the thin film 7a of the first coating solution and the second coating solution containing platinum alcoxides, respectively, are formed in turn on the substrate 4 and then the thin films 6a, 7a are baked in turn in a reductive or oxidative atmosphere to form the thin film consisting of noble metals and the thin film consisting of noble metal oxides in the form of superposed layers, so that no complicated apparatus is required and thus the manufacturing expenses can be easily reduced.

The thicknesses of the thin film 6a consisting of the first coating solution and that of the thin film 7a consisting of the second coating solution are set, for example, by regulating the respective concentrations of the first coating solution and the second coating solution or the rotation frequency of the turning table 2.

The heating temperature in the reductive atmosphere is set within a range of 500 to 600 °C and that in the oxidative atmosphere is set within a range of 300 to 400 °C. For example, N₂ or H₂ can be used as the reductive atmosphere. The rotation frequency of the turning table 2 is set within a range of, for example, 3,000 to 5,000 rpm.

Although the thin film consisting of noble metals and the thin film consisting of noble metal oxides are formed on the substrate 4 in a plurality

of layers in this first preferred embodiment, it is also possible to form the thin film consisting of noble metals or noble metal oxides in a single layer.

In the case where the thin film is formed in a plurality of layers, noble metal alcoxides forming the respective layers may be different from each other and various kinds of metal alcoxides containing noble metal alcoxides as main components or as additives in minor amounts maybe used. In addition, a part of a plurality of layers of thin film can be formed by the use of base metal alcoxides or semiconductor alcoxides, so that it is also possible to form the multi-layer thin film in various kinds of combination, such as metal oxide/noble metal oxide/noble metal and noble metal/metal oxide/semiconductor, depending upon the use of the thin film.

A second preferred embodiment using a noble metal, namely Ir, as an additive to the base metals is described with reference to Figs. 4 to 5. This second preferred embodiment corresponds to the second aspect of the invention.

According to the second preferred embodiment, a suitable quantity of isopropoxy iridium [Ir-(OC₂H₅)₃] as the noble metal alcoxide is added to pentaethoxy tantalum [Ta(OC₂H₅)₅] as a tantalum alcoxide [Ta - (O - R)₅] to prepare a coating solution in the same manner as in the first preferred embodiment.

Referring to Fig. 4, reference numeral 10 designates a vessel containing said coating solution 11 therein. A substrate 4 is immersed in the coating solution 11 and then drawn up to form a thin film on a surface of said substrate 4. After drying, said thin film is baked in an oxidative atmosphere to form a metal oxide thin film 12 consisting of Ta₂O₅ with Ir added on the substrate 4, as shown in Fig. 5. The electrical resistance value of said metal oxide thin film 12 can be regulated to be within a range of high-insulating to low-insulating, for example within about 10⁷ to 10⁴ Ω , by adjusting the molar ratio of isopropoxy iridium added.

The metal oxide thin film 12 is used, for example, as a pH sensor, but oxides of Ir and other noble metals added exhibit a response to pH even influenced by the oxidation and the reduction, so that noble metals, as Ir, when added can improve the response of the metal oxide thin film 12 in the case where the metal oxide thin film 12 is used as a pH sensor.

For example, when the metal oxide thin film 12 is formed on a substrate of ISFET, an ion concentration-measuring electrode superior in response can be constructed.

In addition, although noble metal alcoxides are used as additives in the second preferred embodiment, noble metal alcoxides may be used as main

components and base metal alcoxides may be added to noble metal alcoxides. Further, although the thin film is formed in a single layer on the substrate 4 in the second preferred embodiment, the thin film may be formed in a plurality of layers, as shown in the first preferred embodiment.

As is obvious from the first and second preferred embodiments, noble metal alcoxides can be optionally selected depending upon the use. If a thin film of a coating solution containing for example palladium alcoxides (Pd - O - R, R: - C₃H₇, - C₅H₉) in a concentration of 10 % by weight is formed, then dried and baked, whereby a porous metallic Pd thin film is formed on a substrate of a MOSFET, said porous metallic Pd thin film can be used as a hydrogen sensor.

In addition, if a thin film of a coating solution containing Pt alcoxide is formed on a substrate of a MOSFET and baked in a reductive or oxidative atmosphere, whereby a Pt or PtO thin film is formed, said Pt or PtO thin film can be used as a gas sensor due to the catalytic action thereof.

In the case where a coating solution containing a plurality of alcoxides for use in pH glass response, for example alcoxides of Si, Lt, La, Ti or Ba, is prepared to form a pH-responsive film, and a thin film of noble metal alcoxides is used as an oxidative layer, the adhesion of said oxidative layer to said glass-responsive film can be improved and thus a separation can be suitably prevented.

According to the method of the invention, it is possible to produce a single-component thin film in high efficiency and inexpensively. Also in the case where a multi-component thin film is formed, it is sufficient that a coating solution containing the respective noble metal alcoxides or noble metal alcoxides and base metal alcoxides in mixture is prepared to form the thin film thereof, so that it is unnecessary to use a complicated and large-scaled apparatus for forming a multi-component thin film, and thus it is possible to easily and inexpensively form a multi-component thin film. In addition, since the coating solution contains noble metal alcoxides or noble metal alcoxides and base metal alcoxides in mixture, it is also possible to easily control the crystalline and amorphous structure of the respective ingredients or the compactness of the porous thin film, and thus it is possible to produce a thin film having the structure corresponding to the intended use.

In addition, in the method according to claim 3, the metallic thin film or the metal oxide thin film which is formed from the solution of optional metal alcoxides in the same manner as the above described metallic or metal oxide thin film, is piled up in layers, so that it is possible to produce a thin film having a structure corresponding to various kinds of use by selecting the desired components

of the thin film and setting the number of layers constituting the thin film.

Claims

1. A method of producing a metallic thin film, **characterized in that** a thin film of a solution of at least one noble metal alcoxide is formed on a substrate, then dried and baked either in a reductive atmosphere to form a thin film of noble metals or in an oxidative atmosphere to form a thin film of noble metal oxides.
2. A method of producing a metallic thin film, **characterized in that** a thin film of a solution of metal alcoxides containing at least one noble metal alcoxide as the main component or as additive in minor amounts is formed on a substrate, then dried and baked either in a reductive atmosphere to form a thin film of metals or in an oxidative atmosphere to form a thin film of metal oxides.
3. The method according to claim 1 and/or 2, **characterized in that**, before baking, the film formation is repeated at least one times to pile-up a plurality of thin film layers on said substrate.

Fig.1

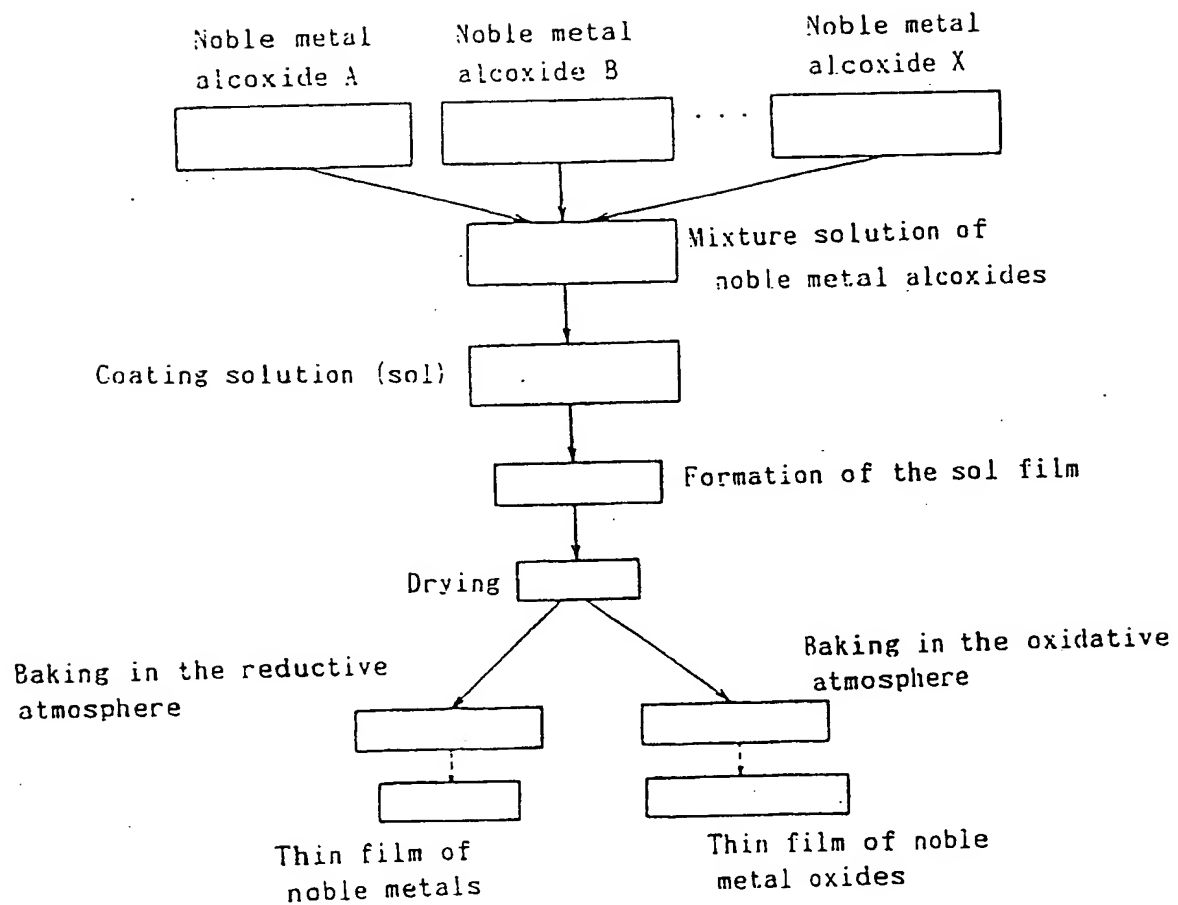


Fig. 2

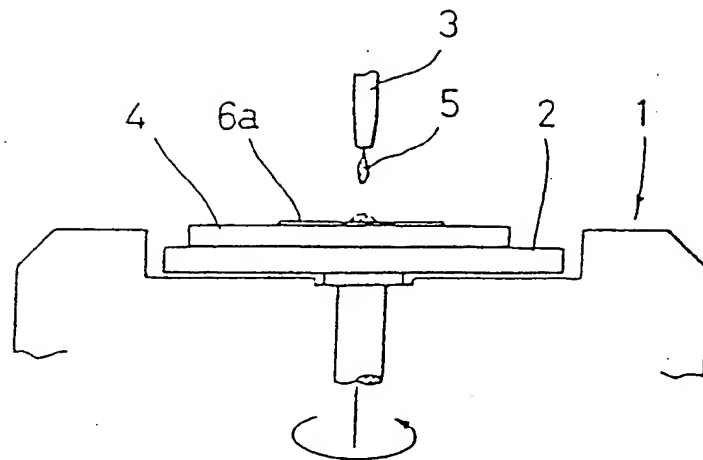


Fig. 3

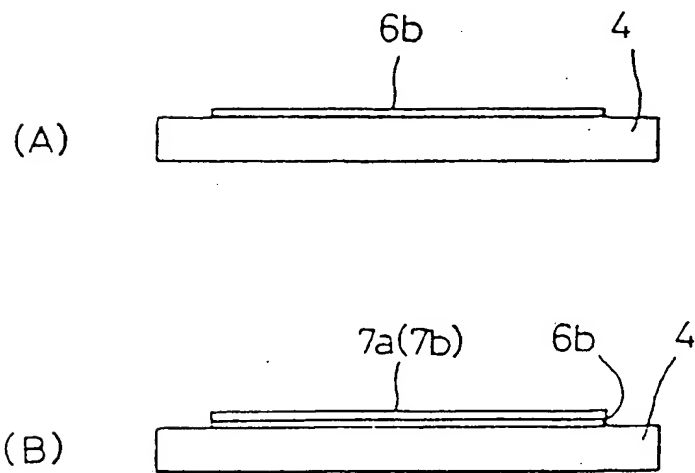


Fig.4

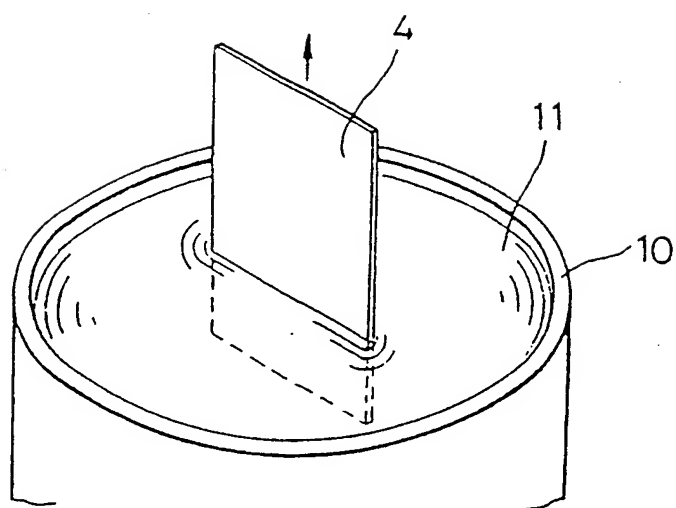
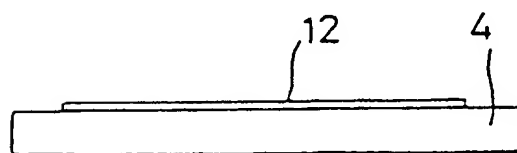


Fig.5



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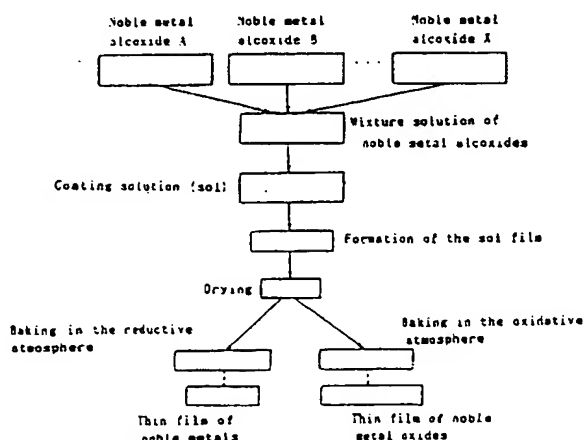
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D-81679 München (DE)(54) **Method of producing metallic thin film.**

(57) A thin film of a solution of at least one noble metal alcoxide is formed on a substrate, then dried and baked either in a reductive atmosphere to produce a thin film of metals or in an oxidative atmosphere to form a thin film of metal oxides. Said solution of noble metal alcoxides may contain merely a single component or a plurality of components. In addition, a solution of metal alcoxides containing at least one noble metal alcoxide as main component or as additive in minor amounts may be used in place of the solution of noble metal alcoxides. Said thin film of metals or metal oxides can be formed as a single layer or as a plurality of layers.

Since the thin film formed on said substrate is baked in said reductive or oxidative atmosphere, not only a single-component thin film but also a multi-component thin film can be inexpensively formed without using a complicated and large-scaled apparatus. In addition, since a solution is used, it is also possible to control the crystalline and amorphous structure of noble metal alcoxides or metal alcoxides or the compactness in the case where a porous thin film is formed.

Fig.1


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EUROPEAN SEARCH REPORT

Application Number
EP 92 10 8247

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claims	CLASSIFICATION OF THE APPLICATION (Int.Cl.5)
A	EP-A-0 316 452 (MATSUSHITA ELECTRIC) * abstract; example 1 * ---	1,2	C23C18/12 C23C18/08
A	PATENT ABSTRACTS OF JAPAN vol. 12, no. 248 (C-511)(3095) 13 July 1988 & JP-A-63 035 780 (FURUKAWA ELECTRIC) * abstract * ---	1,2	
A	JOURNAL OF NON-CRYSTALLINE SOLIDS vol. 100 , 1988 , AMSTERDAM NL pages 1 - 15 R.C. MEHROTRA 'SYNTHESIS AND REACTIONS OF METAL ALKOXIDES' * abstract; table 1 * * page 11, right column - page 12, right column * ---	1,2	
A	THIN SOLID FILMS vol. 165 , November 1988 , LAUSANNE CH pages 317 - 322 K.R. SPECK ET AL 'VANADIUM DIOXIDE FILMS GROWN FROM VANADIUM TETRAISOPROPOXIDE BY THE SOL-GEL PROCESS' * abstract; figure 1 * -----	1,2	
			TECHNICAL FIELDS SEARCHED (Int.Cl.5)
			C23C
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 3 January 1994	Examiner Mettler, R-M
CATEGORY OF CITED DOCUMENTS			
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